Datasheet
SHF 803 P
Broadband Amplifier
### Specifications – SHF 803 P

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Symbol</th>
<th>Unit</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Conditions</th>
</tr>
</thead>
<tbody>
<tr>
<td>High frequency 3 dB point</td>
<td>f_{HIGH}</td>
<td>GHz</td>
<td>40</td>
<td>45</td>
<td>53</td>
<td></td>
</tr>
<tr>
<td>High frequency 6 dB point</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Low frequency 3 dB point</td>
<td>f_{LOW}</td>
<td>kHz</td>
<td></td>
<td>35</td>
<td></td>
<td>non-inverting</td>
</tr>
<tr>
<td>Gain</td>
<td></td>
<td>dB</td>
<td>16</td>
<td>17</td>
<td>18</td>
<td></td>
</tr>
<tr>
<td>Output voltage adjust Voltage Current</td>
<td></td>
<td>V mA</td>
<td>0</td>
<td>10</td>
<td>-5</td>
<td>reduces gain by up to 3 dB</td>
</tr>
<tr>
<td>Gain ripple</td>
<td></td>
<td>dB</td>
<td>±1</td>
<td>±1.5</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Temperature coefficient</td>
<td>T_c</td>
<td>dB/°C</td>
<td>-0.05</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>Noise figure</td>
<td>N_F</td>
<td>dB</td>
<td>6</td>
<td></td>
<td></td>
<td>at 5 GHz</td>
</tr>
<tr>
<td>Output power at 1 dB compression</td>
<td>P_{01dB}</td>
<td>dBm (V)</td>
<td>20 (6.3)</td>
<td>17 (4.5)</td>
<td></td>
<td>&lt;10 GHz &lt;40 GHz</td>
</tr>
<tr>
<td>Output power at 2 dB compression</td>
<td>P_{02dB}</td>
<td>dBm (V)</td>
<td>21 (7.0)</td>
<td>18 (5.1)</td>
<td></td>
<td>&lt;10 GHz &lt;40 GHz</td>
</tr>
<tr>
<td>Output power at 3 dB compression</td>
<td>P_{03dB}</td>
<td>dBm (V)</td>
<td>22 (7.8)</td>
<td>19 (5.6)</td>
<td></td>
<td>&lt;10 GHz &lt;40 GHz</td>
</tr>
<tr>
<td>Jitter</td>
<td></td>
<td>fs</td>
<td>550</td>
<td>700</td>
<td>600</td>
<td>on scope display deconvoluted</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td>output voltage ~4V</td>
</tr>
<tr>
<td>Input return loss</td>
<td>S_{11}</td>
<td>dB</td>
<td>-20</td>
<td>-15</td>
<td>-10</td>
<td>&gt;40 MHz &lt;10 GHz</td>
</tr>
<tr>
<td>Output return loss</td>
<td>S_{22}</td>
<td>dB</td>
<td>-10</td>
<td></td>
<td></td>
<td>&gt;10 GHz &lt;40 GHz</td>
</tr>
<tr>
<td>Maximum input power</td>
<td></td>
<td>dBm</td>
<td>9</td>
<td>10</td>
<td></td>
<td>in operation without power supply</td>
</tr>
<tr>
<td>Rise time/fall time</td>
<td>t_{r/t_f}</td>
<td>ps</td>
<td>9</td>
<td></td>
<td></td>
<td>20%...80%</td>
</tr>
<tr>
<td>Supply voltage</td>
<td></td>
<td>V</td>
<td>9</td>
<td>12</td>
<td></td>
<td>0.55 A, reverse voltage protected</td>
</tr>
<tr>
<td>Power consumption</td>
<td></td>
<td>W</td>
<td>5</td>
<td></td>
<td></td>
<td>using 9 V supply voltage</td>
</tr>
<tr>
<td>Input connector</td>
<td></td>
<td></td>
<td>V (1.85 mm)</td>
<td>female</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Output connector</td>
<td></td>
<td></td>
<td>V (1.85 mm)</td>
<td>male</td>
<td></td>
<td></td>
</tr>
<tr>
<td>Dimensions</td>
<td></td>
<td>mm</td>
<td>51x35x13.5</td>
<td></td>
<td></td>
<td>excluding connectors</td>
</tr>
</tbody>
</table>

The SHF 803 P is a modulator driver suitable for OC-768 applications. Together with high performance, the amplifier is extremely easy to use: a single power supply is all that is needed for operation.

A two stage amplifier design is employed using special monolithic microwave integrated circuits (MMICs) inside special carriers to achieve ultra wide bandwidth and low noise performance. The custom made MMIC carrier is optimized for good input return loss between its interior and the 50 Ohm outside hybrid technology. The computer optimized broadband circuit is individually tuned for minimum pass band ripple. A voltage regulator IC makes the amplifier insensitive to reverse voltage and line ripple.
Output return loss

![Graph showing output return loss]

Group delay

![Graph showing group delay]

Aperture of group delay measurement: 100MHz

Phase response

![Graph showing phase response]
Eye diagrams at 44 Gbps

Measured with 50 GHz sampling module and precision timebase.

Input signal amplitude: 1.005 V
Output signal amplitude: 6.45 V

Input signal amplitude: 642 mV
Output signal amplitude: 4.53 V

Input signal amplitude: 317 mV
Output signal amplitude: 2.27 V
Eye diagrams at 2.5 Gbps

Input signal amplitude: 1.304 V
Output signal amplitude: 7.55 V

Input signal amplitude: 664 mV
Output signal amplitude: 5.00 V

Input signal amplitude: 332 mV
Output signal amplitude: 2.55 V
Jitter and rise time measurements at 44 Gbps

Measured with 63 GHz sampling module and precision timebase.

Input signal

4.3 V output from SHF 803 P

Jitter: 303 fs; Rise time: 11.11 ps

Jitter: 553 fs; Rise time: 12.22 ps

To deconvolute the jitter, we use the following formula:

\[
\text{amplifier jitter} = \sqrt{\left(\text{total jitter}\right)^2 - \left(\text{input signal jitter}\right)^2}
\]

This yields a jitter value of <600 fs.

Saturation power

Gain reduction function

All SHF amplifiers have a feature which allows the output gain to be reduced by up to approximately 3 dB by applying a negative voltage to the gain reduction pin.
Available Options

01: DC return on input (max. ±1.75 V, max. 35 mA)

02: Built-in bias tee on input (max. ±12 V, max. 220 mA)

03: DC return on output (max. ±1.75 V, max. 35 mA)

04: Built-in bias tee on output (max. ±12 V, max. 220 mA)

MT: Special tuning available to optimize performance with E/O modulators
Positive gain slope of up to +3 dB possible

MP: Matches the phase of two amplifiers

The following options cannot be combined:
01 and 02
03 and 04
02 and 04

For other configurations please contact us.
User Instructions

ATTENTION!

Electrostatic sensitive GaAs FET amplifier

1. To prevent damage through static charge build up, cables should be always discharged before connecting them to the amplifier!

2. Attach a 50 Ohm output load before supplying DC power to the amplifier!

3. The supply voltage can be taken from any regular 9...12 V, 1 A DC power supply and can be connected to the supply feed-through filter via an ON / OFF switch.

4. The minimum supply voltage is 9 V. A higher one increases the power dissipation of the internal voltage stabilizer.

5. Using a 3 dB or 6 dB input attenuator will result in a 6 dB or 12 dB increase of the input return loss. For minimal degradation of amplifier rise time, these attenuators should have a bandwidth specification of greater than 50 GHz (V/ 1.85mm attenuators)!

6. An input signal of about 1.6 $V_{pp}$ equivalent to 8 dBm will produce saturated output swing of 7.8$V_{pp}$.

7. Higher input voltages will drive the amplifier’s output stage into saturation, leading to waveform peak clipping.

8. Saturated output voltages can only be used between 10 MHz and 40 GHz without damage while the amplifier is connected to a 50 Ohm precision load with a VSWR of less than 1.2 or better than 20 dB return loss up to 26 GHz.

9. While using a reflective load the output voltage has to be reduced to a safe operating level below 8$V_{pp}$ according to the magnitudes of the reflections.

   ATTENTION: At frequencies up to 20 GHz a capacitive load can be transformed to an inductive one through transmission lines! With an output stage driven into saturation this may lead to the immediate destruction of the amplifier (within a few ps)!

10. The input voltage should never be greater than 1.8 $V_{pp}$ equivalent to 9 dBm input power.

    The input voltage without DC power supplied to the amplifier should never be greater than 2 $V_{pp}$ equivalent to 10 dBm input power.

11. Hint: Pulse shape tuning of the amplifier has been performed after warm up at about 35°C case temperature. Slightly more over and undershoot will be present at low temperature!